

# isc N-Channel MOSFET Transistor

2SK950

#### **DESCRIPTION**

- Drain Current –I<sub>D</sub>= 6A@ T<sub>C</sub>=25 °C
- Drain Source Voltage-
  - : V<sub>DSS</sub>= 500V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

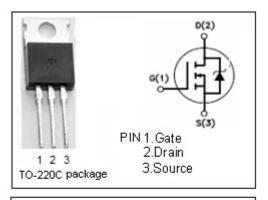
 Designed for high voltage, high speed power switching applications such as switching regulators, converters, solenoid and relay drivers.

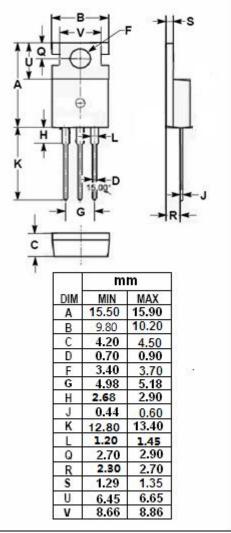
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	500	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-continuous@ TC=25℃ 6		Α
P <sub>tot</sub>	Total Dissipation@TC=25℃ 80		W
T <sub>j</sub>	Max. Operating Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	orage Temperature Range -55~150	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance,Junction to Case	1.56	°C/W
R <sub>th j-a</sub>	j-a Thermal Resistance,Junction to Ambient		°C/W





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#### • ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =10mA	2.1	3.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-stage Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 3.5A		1.0	1.2	Ω
I <sub>GSS</sub>	Gate Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0			500	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> =6A; V <sub>GS</sub> =0		1.0	1.5	V
tr	Rise time	VGS=30V;ID=2.7A; RL=50 Ω		40	70	ns
ton	Turn-on time			65	110	ns
tf	Fall time			60	100	ns
toff	Turn-off time			260	400	ns

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